



深圳市海尔希科技发展有限公司

Shenzhen Haierxi Technology Development Limited

HEX系列产品—HEX0714

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HEX-0714

Halogen Free

**GaAs Hall Sensor**



1. Description

This data sheet is applied to GaAs Hall sensor that HEX.TEC co. Ltd., supplies.

2. Electrical specifications

2.1 Absolute maximum ratings

[Ta=25°C]

Parameter	Symbol	Rating	Unit
Maximum Input Voltage	Vc	8	V
Maximum Power Dissipation	Pmax	150	mW
Operating Temperature Range	Top	-40 ~ +125	°C
Storage Temperature Range	Tst	-40 ~ +150	°C

2.2 General electrical specifications

[Ta=25°C]

Parameter	Symbol	Conditions	Min	Max	Unit
Output Hall Voltage	Vh	Vin=6V, B=50mT	78	102	mV
Input Resistance	Rin	Ic = 0.1mA	1,600	2,400	Ω
Output Resistance	Rout	Ic = 0.1mA	3,200	4,800	Ω
Offset Voltage	Vo	Vin = 6V, B = 0mT	- 8	+ 8	mV

※ Vh=Vhm-Vo ( Vhm : The output voltage measured at 50mT)

2.3 Other electrical specifications (For reference only)

[Ta=25°C]

Parameter	Symbol	Conditions	Min	Max	Unit
Temp. Coeff. of VH	αVh	Average value between Ta = 25~125°C, B=50mT, Ic=5mA	-	- 0.07	%/°C
Temp. Coeff. of Rin	αRin	Average value between Ta = 25~125°C, B=0mT, Ic=0.1mA	-	0.3	%/°C
Linearity	ΔK	B=0.1TG/0.5T Ic=5mA	-	2	%

$$\text{※ } \alpha_{Rin} : \frac{1}{Rin[T1]} \times \frac{Rin[T2] - Rin[T1]}{[T2 - T1]} \times 100 \quad \text{※ } \Delta K : \frac{K[B1] - K[B2]}{[K(B1) + K(B2)]/2} \times 100$$

$$\text{※ } \alpha_{Vh} : \frac{1}{Vh[T1]} \times \frac{Vh[T2] - Vh[T1]}{[T2 - T1]} \times 100$$

T1 = 25°C, T2 = 125°C

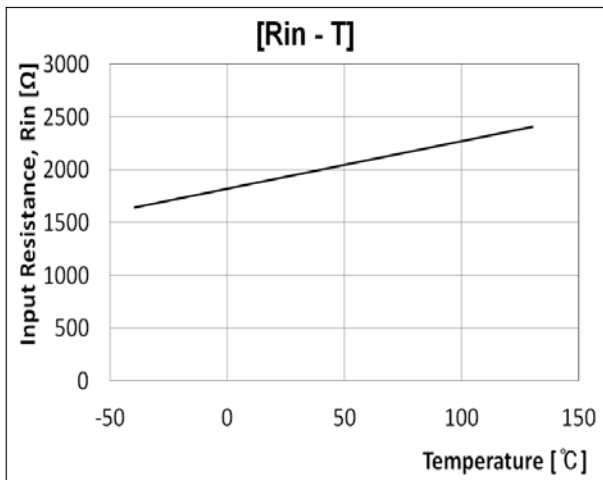
K = Vh / (Ic\*B)

B1 = 0.5T, B2 = 0.1T

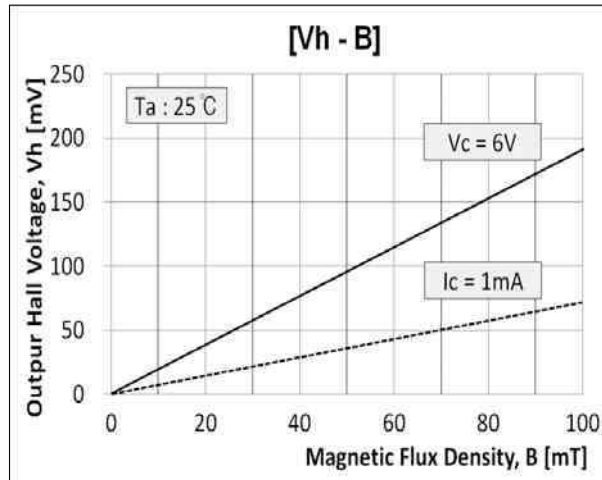


### 2.4 Characteristics graphs

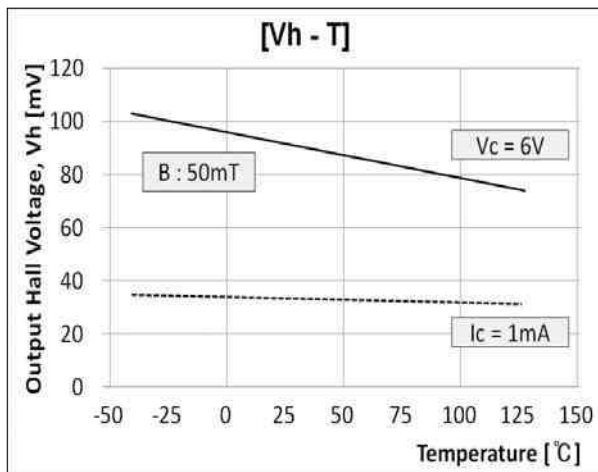
#### ■ Rin-T



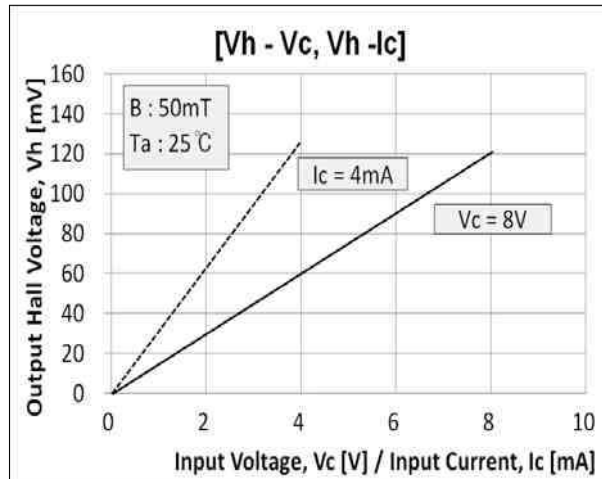
#### ■ Vh-B



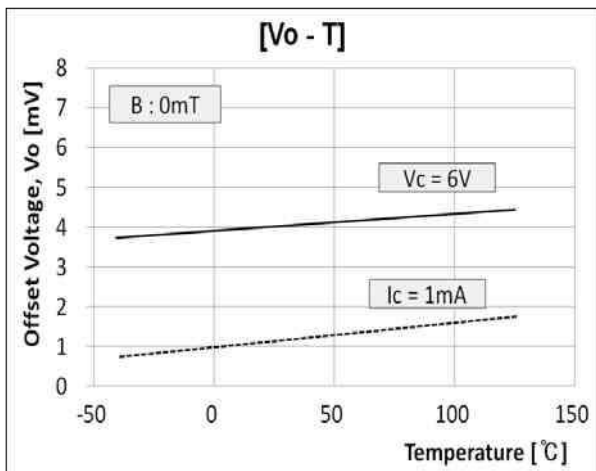
#### ■ Vh-T



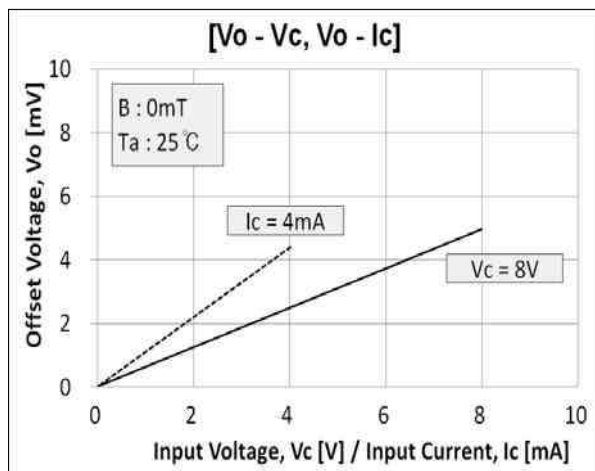
#### ■ Vh-Vc, Vh-Ic



#### ■ Vo-T [For reference only]



#### ■ Vo-Vc [For reference only]



※ Voltage constant operation

※  $V_o$ -T and  $V_o$ - $V_c$  sample :  $R_{in} = 2036[\Omega]$ ,  $V_o = 4.19[\text{mV}]$



### 3. Method for mounting

#### 3.1 Lead frame

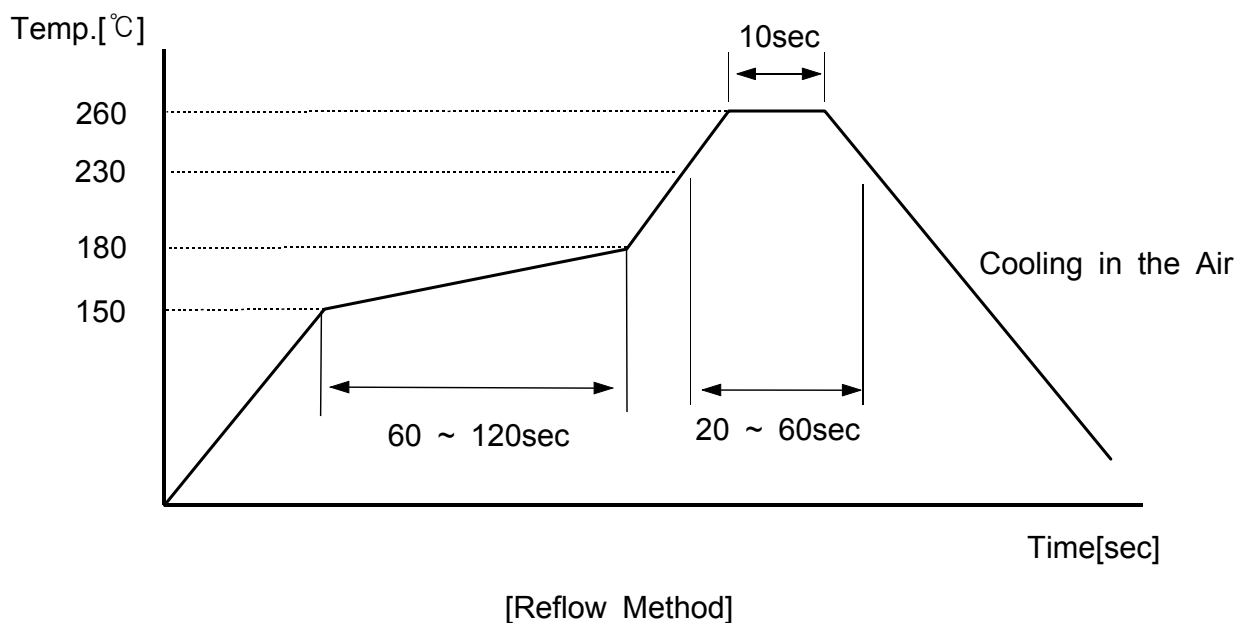
- 1) The material of lead frame is phosphor bronze alloy and the wire bonded surface is plated by silver. The minimum thickness of silver plating is  $2.0\mu\text{m}$ .
- 2) Lead frame is plated by pure Sn and the thickness is controlled by  $4\sim 12\mu\text{m}$ .

#### 3.2 Soldering conditions on PCB

- 1) No rapid heating and cooling is desired.
- 2) Preheating is recommended for  $60 \sim 120\text{secs}$  at  $150 \sim 180^\circ\text{C}$ .
- 3) Reflowing is recommended for  $10\text{seconds}$  at  $260^\circ\text{C}$ .

#### 3.3 Soldering method and temperature

Items	Method	Temperature
Reflow	Soldering by passing the heated zone	Max $260^\circ\text{C}$ in 10sec
Solder Iron	Soldering by solder-iron	Max $350^\circ\text{C}$ in 3sec

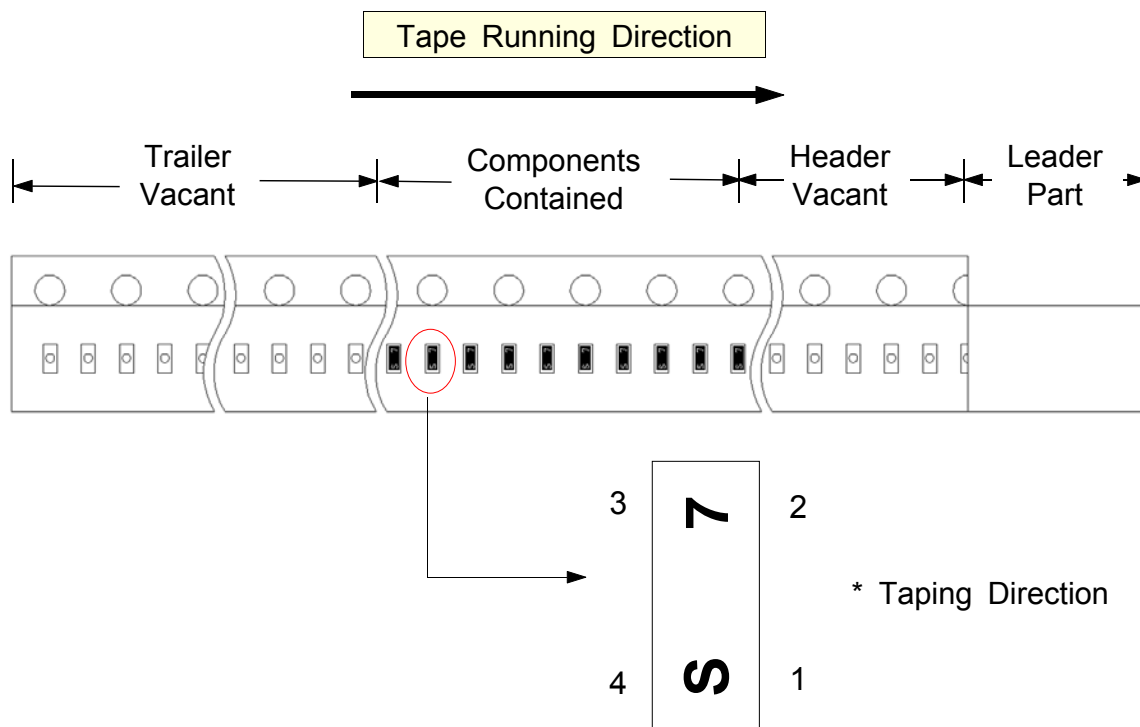




#### 4. Packaging

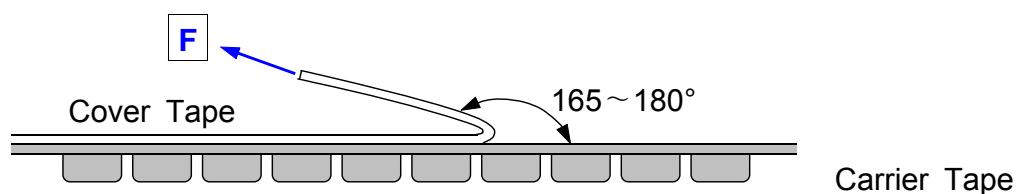
##### 4.1 Taping

- 1) HEX-0714 should be packed and marking is possible to see through cover tape.
- 2) At least, 100mm vacant parts are made both front and rear side of tape.



##### 4.2 Taping specifications

- 1) Pull Strength(F) = 20~70g



- 2) Devices should not run out of a pocket when tape is bent down 15mm curvature.
- 3) Devices should not stick to cover tape.
- 4) Devices should be kept below 40°C and below RH80% in the shade.
- 5) Tape has no joint.